## NSN 5961-01-416-6418

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-416-6418 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.140 inches and 0.163 inches Overall Diameter: Between 0.118 inches and 0.124 inches **Function For Which Designed:** Limiter Joint Electronic Device Engineering Council/jedec/case Outline Designation: Pill-b **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, dc and 180.0 breakdown voltage, dc **Power Rating Per Characteristic:** 10.0 watts small-signal output power, common-base minor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 13499-353-3811 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No